# NSN 5962-01-373-5194

Memory Microcircuit - Page 1 of 1



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## Maximum Power Dissipation Rating:

1.0 watts

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## Features Provided:

Burn in and electrostatic sensitive and programmed and ultraviolet erasable

### Inclosure Material:

Ceramic

## Inclosure Configuration:

Dual-in-line

## Input Circuit Pattern:

15 input

### Case Outline Source And Designator:

D-10 mil-m-38510

## **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 7.0 volts power source

#### Time Rating Per Chacteristic:

250.00 nanoseconds access

#### Memory Device Type:

Rom

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### Terminal Type And Quantity:

28 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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### Demilitarization:

Yes - demil/mli

Fiig:

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